## NSN 5961-01-448-8993

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-448-8993 **Inclosure Material:** Ceramic **Overall Length:** Between 0.110 inches and 0.120 inches **Overall Height:** Between 0.035 inches and 0.047 inches **Overall Width:** Between 0.083 inches and 0.104 inches **End Application:** 6625-01-432-6997 e/i fscm 09553 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakover voltage, dc **Current Rating Per Characteristic:** 1.00 amperes source cutoff current preset **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector absolute **Terminal Type And Quantity:** 3 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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